

Solar Cell Pyramids

Sulaiman, Sulaiman

Introduction: Surface texturing is a beneficial and essential step in the fabrication process of monocrystalline silicon (c-Si) and multicrystalline silicon (mc-Si) solar cells. It leads to an increased front surface area and hence to a larger amount of light coupled into the cell.

Problems/hypothesis: Increase solar cell efficiency by texturing the Si solar cell surface, and therefore increasing the absorption of sunlight. To reduce front surface reflection in Si solar cells,

Procedures/methodology: Texturing: Alkaline etching has been done with KOH and IPA in water for both c-Si and mc-Si wafers.

Surface characterization: The surface topography was studied by means of an Agilent 5420 Atomic Force Microscope [AFM] in tapping mode.

Optical characterization: The optical characterization was done in the wavelength range 200-1200 nm using a Shimadzu SolidSpec-3700 Spectrophotometer with an integrating sphere.

Anti-Reflection Coating: After texturing characterization, a 115nm thick dry SiO₂ layer Anti-Reflection Coating (ARC) was thermally grown on each sample.

Results: The reflectance of the (C-Si) surface is reduced to 7% after texturing and to 0.79% after adding an ARC. In (P.C- Si) the reflectance is reduced to 19% after texturing and to 4.5% after adding an anti-reflective coating. These results have a great significance on the efficiency of solar cells.

Conclusion: Alkaline etching of (C-Si) and (P.C- Si) wafers has been used to perform anisotropic surface texturing. A detailed study of the surface topography and reflection is carried out. It is found that minimum reflectance occurs with a KOH concentration to 1% in the etching solution, and when the texturing time is 20 min and texturing temperature is in the range 80-95°C.